## **Analog Power**

## AM40N06-28D

## N-Channel 60-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r<sub>DS(on)</sub> provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe DPAK saves board space
- Fast switching speed
- High performance trench technology



HALOGEN

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	$r_{DS(on)} m(\Omega) = I_D (A$				
60	$28 @ V_{GS} = 10V$	35			
	$30 @ V_{GS} = 4.5V$	34			





Top View

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)					
Parameter			Limit	Units	
Drain-Source Voltage			60	V	
Gate-Source Voltage		V <sub>GS</sub>	±20	V	
Continuous Drain Current <sup>a</sup>	$T_{\rm C}=25^{\rm o}{\rm C}$	I <sub>D</sub>	35	А	
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	140	A	
Continuous Source Current (Diode Conduction) <sup>a</sup>			35	А	
Power Dissipation <sup>a</sup>	T <sub>C</sub> =25°C	P <sub>D</sub>	50	W	
Operating Junction and Storage Temperature Range		TJ, Tstg	-55 to 175	°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Maximum	Units		
Maximum Junction-to-Ambient <sup>a</sup>	$R_{\theta JA}$	50	°C/W		
Maximum Junction-to-Case	$R_{\theta JC}$	3.0	°C/W		

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

SPECIFICATIONS ( $T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)							
Parameter	Symbol	Test Conditions	Limits			I In:t	
r ar anneter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	1			V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = 20 V$			±100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 48 V, V_{GS} = 0 V$			1	uA	
	*DSS	$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	uA	
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 V, V_{GS} = 10 V$	35			Α	
Drain-Source On-Resistance <sup>A</sup>	r <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_D = 3 \text{ A}$			28	mΩ	
Drain-Source On-Resistance		$V_{GS} = 4.5 \text{ V}, I_D = 2 \text{ A}$			30		
Forward Tranconductance <sup>A</sup>	$g_{fs}$	$V_{DS} = 15 \text{ V}, I_{D} = 3 \text{ A}$		25		S	
Diode Forward Voltage	V <sub>SD</sub>	$I_{s} = 2 A, V_{GS} = 0 V$		1.1		V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg	X = 15 X X = 45 X		26			
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_{D} = 30 \text{ A}$		5		nC	
Gate-Drain Charge	$Q_{gd}$	$I_{\rm D} = 50$ A		13			
Turn-On Delay Time	t <sub>d(on)</sub>			6			
Rise Time	t <sub>r</sub>	$V_{\rm DD}$ = 25 V, $R_{\rm L}$ = 25 $\Omega$ , ID = 30 A,		6		nS	
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GEN} = 10 V$		50		115	
Fall-Time	t <sub>f</sub>			20			

Notes

a. Pulse test:  $PW \le 300$ us duty cycle  $\le 2\%$ .

b. Guaranteed by design, not subject to production testing.

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## Package Information



OMMONTH.	DIMENS.	iinal b	REGNTS	
SYMBOL	MIN	NDH	MAX	
Ε	6.40	6.60	6.731	
L	1.40	152	1.77	
L1	2.743 REF			
L2		.508 BS	C	
L3	0.89	1	1,27	
L4	0.64	I	1.01	
L5	I	۱		
D	6.00	6.10	6.223	
Н	9,40	10,00	10.40	
9	0.64	0.76	0.88	
62	0.77	0.84	1,14	
63	5.21	5,34	5.46	
•	2,	286 BS	C	
A	2.20	2.30	5'36	
A1	0		0.127	
С	0.45	0.50	0.60	
c2	0.45	0.50	0.58	
M	5.30			
EL	4.40	-	1	
8	6	I	10*	